Amendments to the Claims

Please amend claims 7, 22, 24 and 26-28 as show below.

Listing of Claims

This listing of claims will replace all prior versions and listings of claims in the application:

1. (Original) A method of storing failure addresses of a memory cell, said method comprising the steps of:

storing an address and corresponding fail count for a plurality of cells of said memory cell in a register unit until said register unit is full;

determining if a plurality of cells in an input register has a greater fail count than a fail count of a plurality of cells currently stored in said register; and

replacing said address and a corresponding fail count in said register with said address and corresponding fail count in said input register if the fail count of said plurality of cells in said input register is greater than said fail count of said plurality of cells currently stored in said register.

- 2. (Original) The method of claim 1 wherein said step of determining if a plurality of cells in an input register has a greater fail count than a fail count of a plurality of cells currently stored in said register comprises determining if a row in said input register has a greater fail count than a fail count of any row currently stored in said register.
- 3. (Original) The method of claim 2 wherein said step of replacing said address and a corresponding fail count in said register comprises replacing a currently stored row address and a corresponding fail count with a row address and corresponding fail count from said input register.

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4. (Original) The method of claim 4 further comprising a step of replacing said rows stored in said register with redundant rows.

5. (Original) The method of claim 1 wherein said step of determining if a plurality of cells in an input register has a greater fail count than a failure count of a plurality of cells currently stored in said register comprises determining if a column in said input register has a greater fail count than a failure count of any column currently stored in said register.

6. (Original) The method of claim 1 wherein said step of replacing said address and a corresponding fail count in said register comprises replacing said currently stored column address and a corresponding fail count with a column address and corresponding fail count in said input register.

7. (Currently Amended)) The method of claim [[7]] 6 further comprising a step of replacing said columns stored in said register with redundant columns.

8. (Original) A method of storing failure addresses of a memory cell, said method comprising the steps of:

storing a plurality of addresses and corresponding fail counts for a plurality of rows in a register until said register is full;

loading a new row address and a corresponding fail count into an input register; simultaneously comparing said corresponding fail count of said new row address to said plurality of fail counts stored in said register; and

replacing a row address and a corresponding fail count in said register if the corresponding fail count of said new address is greater than a fail count corresponding to said row address stored in said register.

9. (Original) The method of claim 8 further comprising a step of storing a plurality of addresses and corresponding fail counts for a plurality of columns in a register until said register is full.

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10. (Original) The method of claim 9 further comprising a step of loading a new column

address and a corresponding fail count into an input register.

11. (Original) The method of claim 10 further comprising a step of simultaneously

comparing said corresponding fail count of said new column address to all stored fail counts.

12. (Original) The method of claim 11 further comprising a step of replacing a column

address and a corresponding fail count in said register if the corresponding fail count of said new

column address is greater than a fail count of a column address stored in said register.

13. (Original) The method of claim 12 further comprising steps of repeating said steps

of replacing a row address and a corresponding fail count in said register if the corresponding fail

count of said new row address is greater than a fail count of a row address stored in said register

and replacing a column address and a corresponding fail count in said register if the

corresponding fail count of said new column address is greater than a fail count of a column

address stored in said register.

14. (Original) The method of claim 13 further comprising a step of replacing said

column addresses stored in said register with redundant column addresses.

15. (Original) A method of storing failure addresses of a memory cell, said method

comprising the steps of:

storing a plurality of row addresses and corresponding failure counts for rows in a

register until said register is full;

loading a new row address and a corresponding fail count into an input register;

sequentially comparing said corresponding fail count of said new fail address to

all stored fail counts in said register; and

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replacing a row address and a corresponding failure count in said register if the corresponding fail count of said new row address is greater than a failure count of said row stored in said register.

16. (Original) The method of claim 15 further comprising a step of storing a plurality of addresses and corresponding fail counts for a plurality of columns in a register until said register is full.

- 17. (Original) The method of claim 16 further comprising a step of loading a new column address and a corresponding fail count into an input register.
- 18. (Original) The method of claim 17 further comprising a step of simultaneously comparing said corresponding fail count of said new column address to all stored fail counts.
- 19. (Original) The method of claim further comprising a step of replacing a column address and a corresponding fail count in said register if the corresponding fail count of said new column address is greater than a fail count of a column address stored in said register.
- 20. (Original) The method of claim 19 further comprising steps of repeating said steps of replacing a column address and a corresponding fail count in said register if the corresponding fail count of said new column address is greater than a fail count of a column address stored in said register and replacing a row and a corresponding fail count in said register if the corresponding fail count of said new column address is greater than a fail count of a column stored in said register.
- 21. (Original) The method of claim 20 further comprising a step of replacing said columns stored in said register with redundant columns.
- 22. (Currently amended) A memory device having <u>a built in self test circuit including</u> a register storing failure addresses, said memory device comprising:

counts; and

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an input register receiving an input fail address and an input fail count; a register having a plurality of slots storing fail addresses and corresponding fail

register to receive from the input register said input fail count and coupled to one of said slots of said register to receive a fail count of the one of said slots of said register registers, the each said comparator comparing the input fail count of the input register and the fail count of the one of said slots of said register, the input fail count being transferred from the input register when the comparator determines that the input fail count exceeds the fail count.

- 23. (Original) The memory device of claim 22 further comprising a clock signal.
- 24. (Currently amended) The memory device of claim 23 further comprising a switch coupled to said clock signal and the input register, said switch providing said input fail address and said input fail count from the input register to a slot of said register.
- 25. (Original) The memory device of claim 24 wherein said switch closes on a falling edge of said clock signal.
- 26. (Currently amended) The memory device of claim [[22]] <u>24</u> further comprising a plurality of register switches, each register switch of said plurality of register switches being coupled to receive <u>as a switching signal</u> an output of a comparator of said plurality of comparators, each register switch being coupled through said switch to receive the input fail count from the input register when the input switch closes.
- 27. (Currently amended) The memory device of claim 26 wherein each said register switch of said plurality of register switches being is coupled to a slot of said plurality of slots of said register to store the input fail count in the slot of said plurality of slots when the switching signal indicates that the comparator determines that the input fail count exceeds the fail count.

counts;

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28. (Currently amended) The memory device of claim 22 wherein said plurality of comparators are coupled to said clock signal, each said comparator being enabled to compare the input fail count of the input register and the fail count of the one of said slots of said register on a rising edge of said clock signal.

29. (Original) A memory device having a register storing failure addresses, said memory device comprising:

an input register receiving an input fail address and an input fail count; a register having a plurality of slots storing fail addresses and corresponding fail

a plurality of comparators, each comparator being coupled to the input register to receive from the input register an input fail count and coupled to one of said slots of said register to receive a fail count of one of said slots of said register, each said comparator comparing the input fail count of the input register and the fail count of the one of said slots of said register and generating a comparator signal in response to the comparison;

a switch coupled to a clock signal and the input register, said switch providing said input fail address and said input fail count from the input register to a slot of said register in response to the clock signal; and

a plurality of register switches, each register switch being coupled to a respective comparator to receive the comparator signal at an output of [[a]] the respective comparator of said plurality of comparators.